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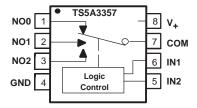
DESCRIPTION

The TS5A3357 is a high-performance, single-pole triple throw (SP3T) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and low input/output capacitance and, thus, causes a very low signal distortion. The break-before-make feature allows transferring of a signal from one port to another, with a minimal signal distortion. This device also offers a low charge injection which makes this device suitable for high-performance audio and data acquisition systems.

APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation

SSOP OR VSSOP PACKAGE (TOP VIEW)



FUNCTION TABLE

| IN1 | IN2 | COM TO NO0 | COM TO NO2 | |
|-----|-----|------------|------------|-----|
| L | L | OFF | OFF | OFF |
| Н | L | ON | OFF | OFF |
| L | Н | OFF | ON | OFF |
| Н | Н | OFF | OFF | ON |

FEATURES

- Specified Break-Before-Make Switching
- Low ON-State Resistance
- High Bandwidth
- Control Inputs are 5.5-V Tolerant
- Low Charge-Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

SUMMARY OF CHARACTERISTICS

 $(V_+ = 5 \text{ V AND } T_A = 25 \, ^{\circ}\text{C})$

| Configuration | 3:1 Multiplexer/Demultiplexer (1 × SP3T) |
|---------------------------|--|
| Number of Channels | 1 |
| ron | 5 Ω |
| $\Delta r_{\sf on}$ | 0.1 Ω |
| ron(flat) | 6.5 Ω |
| tON/tOFF | 6.5 ns/3.7 ns |
| t _{BBM} | 0.5 ns |
| Charge-Injection | 3.4 pC |
| Bandwidth | 334 MHz |
| Off-Isolation | -82 dB at 10 MHz |
| Crosstalk | -62 dB at 10 MHz |
| Total Harmonic Distortion | 0.05% |
| ICOM(OFF) | ±1 μA |
| Package Option | 8 Pin DCT (SM8) or DCU (US8) |



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TEXAS INSTRUMENTS www.ti.com

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ORDERING INFORMATION

| TA | PACKAGE(1) | | ORDERABLE PART NUMBER | TOP-SIDE MARKING(2) |
|---------------|-------------|---------------|--------------------------|------------------------|
| 1000 1- 0500 | SSOP - DCT | Tape and reel | TS5A3357DCTR | JA9 |
| -40°C to 85°C | VSSOP – DCU | Tape and reel | TS5A3357DCUR | JA9_ |

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Absolute Minimum and Maximum Ratings(1)(2)

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------------------------|--|--|------|----------------------|------|
| V ₊ | Supply voltage range(3) | | -0.5 | 6.5 | V |
| V _{NO} V _{COM} | Analog voltage range(3)(4)(5) | | -0.5 | V ₊ + 0.5 | V |
| ΙK | Analog port diode current | V_{NO} , $V_{COM} < 0$ or V_{NO} , $V_{COM} > V_{+}$ | -50 | 50 | mA |
| I _{NO} | On-state switch current | V_{NO} , $V_{COM} = 0$ to V_{+} | -100 | 100 | mA |
| VI | Digital input voltage range(3)(4) | | -0.5 | 6.5 | V |
| lικ | Digital input clamp current | V _I < 0 | -50 | | mA |
| I ₊ I _{GND} | Continuous current through V ₊ or GND | | -100 | 100 | mA |
| θЈΑ | Package thermal impedance(6) | | | 165 | °C/W |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

⁽²⁾ DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

⁽²⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

⁽³⁾ All voltages are with respect to ground unless otherwise specified.

⁽⁴⁾ The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

⁽⁵⁾ This value is limited to 5.5 V maximum.

⁽⁶⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



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ELECTRICAL CHARACTERISTICS FOR 5 V SUPPLY

 $(V_{+} = 4.5 \text{ V TO } 5.5 \text{ V AND } T_{A} = -40 ^{\circ}\text{C TO } 85 ^{\circ}\text{C}) \text{ (UNLESS OTHERWISE NOTED)}$

| PARAMETER | SYMBOL | TEST CONDITION | ONS | TA | ٧+ | MIN | TYP(1) | MAX | UNIT |
|--------------------------------------|----------------------|--|-----------------------------|-------|--------|---------|--------|--------------------|------|
| ANALOG SWITCH | | | | | | | | | |
| Analog Signal Range | ∨ _{СОМ} ,√№ | | | | | 0 | | ٧+ | V |
| Peak On-Resistance | r _{peak} | $0 \le V_{NO} \le V_{+}, I_{COM} = -30 \text{ mA},$ | Switch ON, see Figure 12 | Full | 4.5 V | | | 15 | Ω |
| | | V 0.1 20 A | | 25 °C | | | 5 | 7 | |
| | | $V_{NO} = 0$, $I_{COM} = 30$ mA | | Full | | | | 7 | |
| On-Resistance | _ | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | Switch ON, | 25 °C | 4.5 V | | 6 | 12 | Ω |
| On-Resistance | ron | $V_{NO} = 2.4 \text{ V}, I_{COM} = -30 \text{ mA}$ | see Figure 12 | Full | 4.5 V | | | 12 | 52 |
| | | V _{NO} = 4.5 V, I _{COM} = -30 mA | | 25 °C | | | 7 | 15 | |
| | | VNO = 4.5 V, ICOM = -30 IIIA | | Full | | | | 15 | |
| On-Resistance match between channels | Δr_{on} | $V_{NO} = 3.15 \text{ V}, I_{COM} = -30 \text{ mA},$ | Switch ON, see Figure 12 | 25 °C | 4.5 V | | 0.1 | | Ω |
| On-Resistance flatness | ron(flat) | $0 \le V_{NO} \le V_+$, $I_{COM} = -30 \text{ mA}$ | Switch ON, see Figure 12 | 25 °C | 5 V | | 6.5 | | Ω |
| NO Off-Leakage | | V 04-V V V 4-0 | Switch OFF, | 25 °C | F.F.V. | -0.1 | | 0.1 | ^ |
| Current | INO(OFF) | $V_{NO} = 0 \text{ to } V_+, V_{COM} = V_+ \text{ to } 0,$ | see Figure 13 | Full | 5.5 V | -1 | | 1 | μΑ |
| COM Off-Leakage | 1 | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | Switch OFF, | 25 °C | 5.5 V | -0.1 | | 0.1 | |
| Current | ICOM(OFF) | $V_{NO} = 0 \text{ to } V_+, V_{COM} = V_+ \text{ to } 0,$ | see Figure 13 | Full | 5.5 V | -1 | | 1 | μΑ |
| NO On-Leakage | lua (aus | $V_{NO} = 0$ to V_+ , $V_{COM} = Open$, | Switch ON, | 25 °C | 5.5 V | -0.1 | | 0.1 | ^ |
| Current | INO(ON) | VNO = 0 to v+, vCOM = Open, | see Figure 13 | Full | 5.5 V | -1 | | 1 | μΑ |
| COM On-Leakage | la a | V_{NO} = Open, V_{COM} = 0 to V_{+} , | Switch ON, | 25 °C | 5.5 V | -0.1 | | 0.1 | |
| Current | ICOM(ON) | VNO = Oberi, vCOM = 0 to v+, | see Figure 13 | Full | 5.5 V | -1 | | 1 | μΑ |
| DIGITAL INPUTS (I | N1, IN2)(2) | | | | | | | | |
| Input Logic High | VIH | | | Full | | 0.7 × V | + | 5.5 | V |
| Input Logic Low | V _{IL} | | | Full | | 0 | (|).3×V ₊ | V |
| Input Leakage | | | | 25 °C | | | | 0.1 | |
| Current | ¹IH, ¹IL | V _{IN} = 5.5 V or 0 | | Full | 5.5 V | | | 1 | μΑ |

⁽¹⁾ All typical values are at $V_+ = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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Electrical Characteristics for 5 V Supply (continued) (V+ = 4.5 V TO 5.5 V AND TA = -40 °C TO 85 °C) (UNLESS OTHERWISE NOTED)

| PARAMETER | SYMBOL | TEST CONI | DITIONS | TA | ٧+ | MIN | TYP(1) | MAX | UNIT |
|------------------------------|-----------------------|---|--|---------------|----------------|------------|--------|----------|------|
| DYNAMIC | | | | | | | | | |
| Turn-On Time | ton | $V_{NO} = V_{+} \text{ or GND,}$ $R_{L} = 500 \Omega,$ | C _L = 35 pF, see Figure 15 | 25 °C Full | 4.5 V to 5.5 V | 1.5 1.5 | | 6.5 7 | ns |
| Turn-Off Time | tOFF | $V_{NO} = V_{+} \text{ or GND},$ $R_{1} = 500 \Omega,$ | C _L = 35 pF, see Figure 15 | 25 °C Full | 4.5 V to 5.5 V | 0.8 | | 3.7 | ns |
| Break-Before-Make Time | t _{BBM} | $V_{NO} = V_{+},$ $R_{L} = 500 \Omega,$ | C _L = 35 pF, see Figure 16 | 25 °C Full | 4.5 V to 5.5 V | 0.5 | | | ns |
| Charge Injection | Q _C | C _L = 0.1 nF, V _{GEN} = 0 V, | see Figure 20 | 25 °C | 5 V | | 3.4 | | pC |
| NO Off-Capacitance | C _{NO(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 5 V | | 4.5 | | pF |
| COM Off-Capacitance | C _{COM(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 5 V | | 10.5 | | pF |
| NO On-Capacitance | C _{NO(ON)} | V _{NO} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 5 V | | 17 | | pF |
| COM On-Capacitance | C _{COM(ON)} | V _{COM} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 5 V | | 17 | | pF |
| Digital Input Capacitance | C _{IN} | $V_{IN} = V_{+}$ or GND, | see Figure 14 | 25 °C | 5 V | | 3 | | pF |
| Bandwidth | BW | R_L = 50 Ω, Switch ON, | see Figure 17 | 25 °C | 4.5 V to 5.5 V | | 334 | | MHz |
| Off-Isolation | O _{ISO} | $R_L = 50 \Omega$, f = 10 MHz, | Switch OFF, see Figure 18 | 25 °C | 4.5 V to 5.5 V | | -82 | | dB |
| Crosstalk | X _{TALK} | $R_L = 50 \Omega$, f = 10 MHz, | Switch ON, see Figure 19 | 25 °C | 4.5 V to 5.5 V | | -62 | | dB |
| Total Harmonic Distortion | THD | $R_L = 600 \Omega,$ $C_L = 50 pF,$ | f = 20 Hz to 20 kHz, see Figure 21 | 25 °C | 5 V | | 0.05 | | % |
| SUPPLY | • | • | | • | • | | | | |
| Positive Supply Current | 1+ | $V_{IN} = V_{+}$ or GND, | Switch ON or OFF | 25 °C Full | 5.5 V | | | 1 10 | μΑ |

⁽¹⁾ All typical values are at $V_+ = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



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Electrical Characteristics for 3.3 V Supply

 $(V_{+} = 3 \text{ V TO } 3.6 \text{ V AND } T_{A} = -40 \,^{\circ}\text{C TO } 85 \,^{\circ}\text{C}) \text{ (UNLESS OTHERWISE NOTED)}$

| PARAMETER | SYMBOL | TEST CONDITIO | ONS | TA | ٧+ | MIN TY | P(1) N | IAX | UNIT |
|--|-----------------------------------|--|-----------------------------|---------------|-------|----------------------|--------|------------------|------|
| ANALOG SWITCH | • | | | | | • | | | |
| Analog Signal Range | V _{СОМ} , √NО | | | | | 0 | | ٧+ | V |
| Peak On-Resistance | r _{peak} | $0 \le V_{NO} \le V_{+}, I_{COM} = -24 \text{ mA},$ | Switch ON, see Figure 12 | Full | 3 V | | | 25 | Ω |
| | | V 0VI 04 A | | 25 °C | | | 6.5 | 9 | |
| O- Di-t | | $V_{NO} = 0 \text{ V}, I_{COM} = 24 \text{ mA}$ | Switch ON, | Full | 0.1/ | | | 9 | |
| On-Resistance | ron | V 0VI 04A | see Figure 12 | 25 °C | 3 V | | 9 | 20 | Ω |
| | | $V_{NO} = 3 \text{ V}, I_{COM} = -24 \text{ mA}$ | | Full | | | | 20 | |
| On-Resistance match between channels | Δr_{on} | V _{NO} = 2.1 V, I _{COM} = -24 mA, | Switch ON, see Figure 12 | 25 °C | 3 V | | 0.1 | | Ω |
| On-Resistance flatness | ron(flat) | $0 \le V_{NO} \le V_+,$ $I_{COM} = -24 \text{ mA},$ | Switch ON, see Figure 12 | 25 °C | 3.3 V | | 13.5 | | Ω |
| NO Off-Leakage | | V 0. V V V 1. 0 | Switch OFF, | 25 °C | 0.01/ | -0.1 | | 0.1 | |
| Current | INO(OFF) | $V_{NO} = 0 \text{ to } V_+, V_{COM} = V_+ \text{ to } 0,$ | see Figure 13 | Full | 3.6 V | -1 | | 1 | μΑ |
| COM Off-Leakage | | V 0 to V V V to 0 | Switch OFF, | 25 °C | 261/ | -0.1 | | 0.1 | ^ |
| Current | ICOM(OFF) | $V_{NO} = 0 \text{ to } V_+, V_{COM} = V_+ \text{ to } 0,$ | see Figure 13 | Full | 3.6 V | -1 | | 1 | μΑ |
| NO On-Leakage | 1 | Very Oto V. Very Open | Switch ON, | 25 °C | 3.6 V | -0.1 | | 0.1 | ^ |
| Current | INO(ON) | $V_{NO} = 0$ to V_+ , $V_{COM} = Open$, | see Figure 13 | Full | 3.0 V | -1 | | 1 | μΑ |
| COM On-Leakage | 1 | \\ Open \\ 0 to \\. | Switch ON, | 25 °C | 3.6 V | -0.1 | | 0.1 | ^ |
| Current | ICOM(ON) | $V_{NO} = Open, V_{COM} = 0 \text{ to } V_+,$ | see Figure 13 | Full | 3.0 V | -1 | | 1 | μΑ |
| DIGITAL INPUTS (| IN1, IN2)(2) | | | | | | | | |
| Input Logic High | VIH | | | Full | | 0.7 × V ₊ | | 5.5 | V |
| Input Logic Low | V _{IL} | | | Full | | 0 | 0.3 > | < V ₊ | V |
| Input Leakage Current | I _{IH} , I _{IL} | V _{IN} = 5.5 V or 0 | | 25 °C Full | 3.6 V | -1 | | 0.1 | μА |

⁽¹⁾ All typical values are at $V_+ = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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Electrical Characteristics for 3.3 V Supply (continued) (V+ = 3 V TO 3.6 V AND TA = -40 °C TO 85 °C) (UNLESS OTHERWISE NOTED)

| PARAMETER | SYMBOL | TEST COND | DITIONS | TA | ٧+ | MIN | TYP(1) | MAX | UNIT |
|------------------------------|-----------------------|---|------------------------------|-------|--------------|-----|--------|-----|------|
| DYNAMIC | • | | | • | • | | | | |
| Turn-On Time | t | $V_{NO} = V_{+}$ or GND, | C _L = 50 pF, | 25 °C | 3 V to 3.6 V | 2 | | 9.5 | 20 |
| Tuill-Oil Tillie | tON | $R_L = 500 \Omega$, | see Figure 15 | Full | 3 V 10 3.6 V | 2 | | 11 | ns |
| Turn-Off Time | tOFF | $V_{NO} = V_{+}$ or GND, | $C_L = 50 \text{ pF},$ | 25 °C | 3 V to 3.6 V | 1.3 | | 5.1 | ns |
| | OFF | $R_L = 500 \Omega$, | see Figure 15 | Full | 3 V 10 3.0 V | 1.5 | | 5.5 | 110 |
| Break-Before-Make | t _{BBM} | $V_{NO} = V_{+}$ | $C_L = 35 \text{ pF},$ | 25 °C | 3 V to 3.6 V | 0.5 | | | ns |
| Time | ,DDINI | $R_L = 500 \Omega$ | see Figure 16 | Full | 0 7 10 0.0 7 | 0.5 | | | 110 |
| Charge Injection | $Q_{\mathbb{C}}$ | $C_L = 0.1 \text{ nF, } V_{GEN} = 0 \text{ V,}$ | see Figure 20 | 25 °C | 3.3 V | | 1.75 | | рC |
| NO Off-Capacitance | C _{NO(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 3.3 V | | 4.5 | | pF |
| COM Off-Capacitance | C _{COM(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 3.3 V | | 10.5 | | pF |
| NO On-Capacitance | C _{NO(ON)} | V _{NO} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 3.3V | | 17 | | pF |
| COM On-Capacitance | C _{COM(ON)} | V _{COM} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 3.3 V | | 17 | | pF |
| Digital Input Capacitance | C _{IN} | $V_{IN} = V_{+}$ or GND, | see Figure 14 | 25 °C | 3.3 V | | 3 | | pF |
| Bandwidth | BW | $R_L = 50 \Omega$, Switch ON, | see Figure 17 | 25 °C | 3 V to 3.6 V | | 327 | | MHz |
| Off-Isolation | O _{ISO} | $R_L = 50 \Omega$, f = 10 MHz, | Switch OFF, see Figure 18 | 25 °C | 3 V to 3.6 V | | -82 | | dB |
| Crosstalk | X _{TALK} | $R_L = 50 \Omega$, f = 10 MHz, | Switch ON, see Figure 19 | 25 °C | 3 V to 3.6 V | | -62 | | dB |
| SUPPLY | | | | | | | | | |
| Positive Supply | 1. | V OND | 0t-1 0N 055 | 25 °C | 201/ | | | 1 | A |
| Current | 1+ | $V_{IN} = V_{+}$ or GND, | Switch ON or OFF | Full | 3.6 V | | | 10 | μΑ |

⁽¹⁾ All typical values are at $V_{+} = 3.3 \text{ V}$, $T_{A} = 25^{\circ}\text{C}$.



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Electrical Characteristics for 2.5 V Supply

 $(V_{+} = 2.3 \text{ V TO } 2.7 \text{ V AND } T_{A} = -40 ^{\circ}\text{C TO } 85 ^{\circ}\text{C}) \text{ (UNLESS OTHERWISE NOTED)}$

| PARAMETER | SYMBOL | TEST CONDITIO | NS | TA | ٧+ | MIN | TYP(1) | MAX | UNIT |
|--|------------------------------------|--|-----------------------------|-------|-------|----------|------------|---------------------|------|
| ANALOG SWITCH | • | | | | | • | | | |
| Analog Signal Range | V _{COM} , V _{NO} | | | | | 0 | | ٧+ | V |
| Peak On-Resistance | r _{peak} | $0 \le V_{NO} \le V_{+}, I_{COM} = -8 \text{ mA},$ | Switch ON, see Figure 12 | Full | 2.3 V | | | 50 | Ω |
| | | V 0VI 0A | | 25 °C | | | 8 | 12 | |
| O- Di-t | | $V_{NO} = 0 \text{ V}, I_{COM} = 8 \text{ mA}$ | Switch ON, | Full | 0.01/ | | | 12 | |
| On-Resistance | r _{on} | V 00VI 0A | see Figure 12 | 25 °C | 2.3 V | | 11 | 30 | Ω |
| | | $V_{NO} = 2.3 \text{ V}, I_{COM} = -8 \text{ mA}$ | | Full | | | | 30 | |
| On-Resistance match between channels | Δr_{on} | V _{NO} = 1.6 V, I _{COM} = -8 mA, | Switch ON, see Figure 12 | 25 °C | 2.3 V | | 0.3 | | Ω |
| On-Resistance flatness | ron(flat) | $0 \le V_{NO} \le V_+,$ $I_{COM} = -8 \text{ mA},$ | Switch ON, see Figure 12 | 25 °C | 2.5 V | | 39 | | Ω |
| NO Off-Leakage | İ., | | Switch OFF, | 25 °C | | -0.1 | | 0.1 | |
| Current | INO(OFF) | $V_{NO} = 0 \text{ to } V_+, V_{COM} = V_+ \text{ to } 0,$ | see Figure 13 | Full | 2.7 V | -1 | | 1 | μΑ |
| COM Off-Leakage | | V 0 to V V V to 0 | Switch OFF, | 25 °C | 2.7 V | -0.1 | | 0.1 | |
| Current | ICOM(OFF) | $V_{NO} = 0 \text{ to } V_+, V_{COM} = V_+ \text{ to } 0,$ | see Figure 13 | Full | 2.7 V | -1 | | 1 | μΑ |
| NO On-Leakage | lua (aun | $V_{NO} = 0$ to V_+ , $V_{COM} = Open$, | Switch ON, | 25 °C | 2.7 V | -0.1 | | 0.1 | |
| Current | INO(ON) | VNO = 0 to v+, vCOM = Open, | see Figure 13 | Full | 2.1 V | -1 | | 1 | μΑ |
| COM On-Leakage | loomon | V_{NO} = Open, V_{COM} = 0 to V_+ , | Switch ON, | 25 °C | 2.7 V | -0.1 | | 0.1 | μA |
| Current | ICOM(ON) | VNO = Open, VCOM = 0 to V+, | see Figure 13 | Full | 2.1 V | -1 | | 1 | μΑ |
| DIGITAL INPUTS (I | N1, IN2)(2) | | | | | | | | |
| Input Logic High | VIH | | | Full | | 0.75 × V | ' + | 5.5 | V |
| Input Logic Low | V _{IL} | | | Full | | 0 | 0.: | 25 × V ₊ | V |
| Input Leakage | lu e lu | V = 5.5 V.or 0 | | 25 °C | 2.3 V | | | 0.1 | ^ |
| Current | I _{IH} , I _{IL} | V _{IN} = 5.5 V or 0 | | Full | 2.5 V | | | 1 | μΑ |

⁽¹⁾ All typical values are at $V_+ = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, *Implications* of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics for 2.5 V Supply (continued) (V+ = 2.3 V TO 2.7 V AND TA = -40 °C TO 85 °C) (UNLESS OTHERWISE NOTED)

| PARAMETER | SYMBOL | TEST COND | DITIONS | TA | ٧+ | MIN | TYP(1) | MAX | UNIT |
|------------------------------|-----------------------|---|------------------------------|-------|----------------|-----|--------|------|------|
| DYNAMIC | | | | | | | | | |
| Turn-On Time | tou | $V_{NO} = V_{+} \text{ or GND,}$ | C _L = 50 pF, | 25 °C | 2.3 V to 2.7 V | 3 | | 15 | ns |
| Tuni-On Time | tON | $R_L = 500 \Omega$ | see Figure 15 | Full | 2.3 V 10 2.7 V | 3 | | 16.5 | 115 |
| Turn-Off Time | tOFF | $V_{NO} = V_{+}$ or GND, | $C_L = 50 \text{ pF},$ | 25 °C | 2.3 V to 2.7 V | 2 | | 7.2 | ns |
| | OFF | $R_L = 500 \Omega$ | see Figure 15 | Full | 2.0 V 10 2.7 V | 2 | | 7.8 | 113 |
| Break-Before-Make | t _{BBM} | $V_{NO} = V_{+}$ | $C_L = 35 pF$, | 25 °C | 2.3 V to 2.7 V | 0.5 | | | ns |
| Time | 'DDIVI | $R_L = 500 \Omega$ | see Figure 16 | Full | 2.0 1 10 2.7 1 | 0.5 | | | 110 |
| Charge Injection | $Q_{\mathbb{C}}$ | $C_L = 0.1 \text{ nF, } V_{GEN} = 0 \text{ V,}$ | see Figure 20 | 25 °C | 2.5 V | | 1.15 | | рC |
| NO Off-Capacitance | C _{NO(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 2.5 V | | 4.5 | | pF |
| COM Off-Capacitance | C _{COM(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 2.5 V | | 10.5 | | pF |
| NO On-Capacitance | C _{NO(ON)} | V _{NO} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 2.5V | | 17 | | pF |
| COM On-Capacitance | C _{COM(ON)} | V _{COM} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 2.5 V | | 17 | | pF |
| Digital Input Capacitance | C _{IN} | $V_{IN} = V_{+}$ or GND, | see Figure 14 | 25 °C | 2.5 V | | 3 | | pF |
| Bandwidth | BW | $R_L = 50 \Omega$, Switch ON, | see Figure 17 | 25 °C | 2.3 V to 2.7 V | | 320 | | MHz |
| Off-Isolation | O _{ISO} | $R_L = 50 \Omega$, f = 10 MHz, | Switch OFF, see Figure 18 | 25 °C | 2.3 V to 2.7 V | | -81 | | dB |
| Crosstalk | X _{TALK} | $R_L = 50 \Omega$, f = 10 MHz, | Switch ON, see Figure 19 | 25 °C | 2.3 V to 2.7 V | | -61 | | dB |
| SUPPLY | • | | | • | | | | | |
| Positive Supply | | ., ., ., ., | 0 11 011 077 | 25 °C | 0.71/ | | | 1 | |
| Current | 1+ | $V_{IN} = V_{+}$ or GND, | Switch ON or OFF | Full | 2.7 V | | | 10 | μΑ |

⁽¹⁾ All typical values are at $V_+ = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



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Electrical Characteristics for 1.8 V Supply

 $(V_{+} = 1.65 \text{ V TO } 1.95 \text{ V AND } T_{A} = -40 ^{\circ}\text{C TO } 85 ^{\circ}\text{C}) \text{ (UNLESS OTHERWISE NOTED)}$

| PARAMETER | SYMBOL | TEST C | ONDITIONS | TA | ٧+ | MIN TYP | (1) MA | UNIT |
|--|-----------------------------------|--|-----------------------------|-------|---------|-----------------------|----------|------|
| ANALOG SWITCH | ' | • | | ' | | • | | |
| Analog Signal Range | V _{СОМ} , √NО | | | | | 0 | V. | , V |
| Peak On-Resistance | r _{peak} | $0 \le V_{NO} \le V_+,$ $I_{COM} = -4 \text{ mA},$ | Switch ON, see Figure 12 | Full | 1.65 V | | 15 | Ω |
| | | V _{NO} = 0 V, | | 25 °C | | | 10 2 |) |
| On-Resistance | - | I _{COM} = 4 mA | Switch ON, | Full | 1.65 V | | 2 | Ω |
| On-Resistance | ron | V _{NO} = 1.8 V, | see Figure 12 | 25 °C | 1.05 V | | 17 5 |) 12 |
| | | $I_{COM} = -4 \text{ mA}$ | | Full | | | 5 |) |
| On-Resistance match between channels | Δr_{on} | V _{NO} = 1.15 V, I _{COM} = -4 mA, | Switch ON, see Figure 12 | 25 °C | 1.65 V | | 0.3 | Ω |
| On-Resistance flatness | ron(flat) | $0 \le V_{NO} \le V_+,$ $I_{COM} = -4 \text{ mA},$ | Switch ON, see Figure 12 | 25 °C | 1.8 V | | 140 | Ω |
| NO Off-Leakage | | $V_{NO} = 0 \text{ to } V_{+}$ | Switch OFF, | 25 °C | | -0.1 | 0. | |
| Current | INO(OFF) | $V_{COM} = V_{+}$ to 0, | see Figure 13 | Full | 1.95 V | -1 | | μA |
| COM Off-Leakage | | $V_{NO} = 0 \text{ to } V_{+},$ | Switch OFF, | 25 °C | 4.05.1/ | -0.1 | 0. | |
| Current | COM(OFF) | $V_{COM} = V_{+}$ to 0, | see Figure 13 | Full | 1.95 V | -1 | | μA |
| NO On-Leakage | | $V_{NO} = 0 \text{ to } V_{+}$ | Switch ON, | 25 °C | 4.05.1/ | -0.1 | 0. | |
| Current | INO(ON) | V _{COM} = Open, | see Figure 13 | Full | 1.95 V | -1 | | μA |
| COM On-Leakage | | V _{NO} = Open, | Switch ON, | 25 °C | | -0.1 | 0. | |
| Current | ICOM(ON) | $V_{COM} = 0 \text{ to } V_+,$ | see Figure 13 | Full | 1.95 V | -1 | | μA |
| DIGITAL INPUTS (I | N1, IN2)(2) | | | | | • | | |
| Input Logic High | VIH | | | Full | | 0.75 × V ₊ | 5. | 5 V |
| Input Logic Low | V_{IL} | | | Full | | 0 | 0.25 × V | V |
| Input Leakage | | | | 25 °C | | | 0. | |
| Current | I _{IH} , I _{IL} | $V_{IN} = 5.5 \text{ V or } 0$ | | Full | 1.95 V | | | μA |

⁽¹⁾ All typical values are at $V_{+} = 1.8 \text{ V}$, $T_{A} = 25^{\circ}\text{C}$.

⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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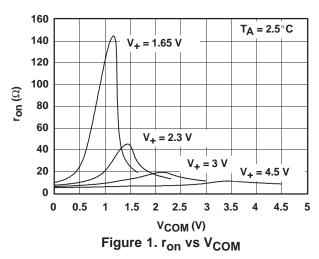
Electrical Characteristics for 1.8 V Supply (continued) (V+ = 1.65 V TO 1.95 V AND T_A = -40 $^{\circ}\text{C}$ TO 85 $^{\circ}\text{C}$) (UNLESS OTHERWISE NOTED)

| PARAMETER | SYMBOL | TEST COND | DITIONS | TA | ٧+ | MIN | TYP(1) | MAX | UNIT |
|------------------------------|-----------------------|---|------------------------------|-------|------------------|-----|--------|------|------|
| DYNAMIC | • | | | | | | | | |
| Turn-On Time | tou | $V_{NO} = V_{+} \text{ or GND,}$ | C _L = 50 pF, | 25 °C | 1.65 V to 1.95 V | 5 | | 32 | ns |
| Tulli-Oli Tillie | tON | $R_L = 500 \Omega$ | see Figure 15 | Full | 1.65 V to 1.95 V | 5 | | 34 | 115 |
| Turn-Off Time | tOFF | $V_{NO} = V_{+} \text{ or GND},$ | $C_L = 50 pF$, | 25 °C | 1.65 V to 1.95 V | 3 | | 14 | ns |
| | OFF | $R_L = 500 \Omega$, | see Figure 15 | Full | 1.00 7 10 1.00 7 | 3 | | 14.5 | 110 |
| Break-Before-Make | t _{BBM} | V _{NO} = V ₊ , | $C_L = 35 \text{ pF},$ | 25 °C | 1.65 V to 1.95 V | 0.5 | | | ns |
| Time | -DDIVI | $R_L = 500 \Omega$, | see Figure 16 | Full | | 0.5 | | | |
| Charge Injection | QC | $C_L = 0.1 \text{ nF, } V_{GEN} = 0 \text{ V,}$ | see Figure 20 | 25 °C | 1.8 V | | 0.3 | | pC |
| NO Off-Capacitance | C _{NO(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 1.8 V | | 4.5 | | pF |
| COM Off-Capacitance | C _{COM(OFF)} | V _{NO} = V ₊ or GND, Switch OFF, | see Figure 14 | 25 °C | 1.8 V | | 10.5 | | pF |
| NO On-Capacitance | C _{NO(ON)} | V _{NO} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 1.8V | | 17 | | pF |
| COM On-Capacitance | C _{COM(ON)} | V _{COM} = V ₊ or GND, Switch ON, | see Figure 14 | 25 °C | 1.8 V | | 17 | | pF |
| Digital Input Capacitance | C _{IN} | $V_{IN} = V_{+}$ or GND, | see Figure 14 | 25 °C | 1.8 V | | 3 | | pF |
| Bandwidth | BW | R_L = 50 Ω, Switch ON, | see Figure 17 | 25 °C | 1.65 V to 1.95 V | | 341 | | MHz |
| Off-Isolation | O _{ISO} | $R_L = 50 \Omega$, f = 10 MHz, | Switch OFF, see Figure 18 | 25 °C | 1.65 V to 1.95 V | | -81 | | dB |
| Crosstalk | X _{TALK} | R_L = 50 Ω, f = 10 MHz, | Switch ON, see Figure 19 | 25 °C | 1.65 V to 1.95 V | | -61 | | dB |
| SUPPLY | | <u> </u> | | | | | | | |
| Positive Supply | 1. | Very Ver CND | Switch ON or OFF | 25 °C | 4.05.1/ | | | 1 | ^ |
| Current | 1+ | $V_{IN} = V_{+}$ or GND, | Switch ON or OFF | Full | 1.95 V | | | 10 | μΑ |

⁽¹⁾ All typical values are at $V_{+} = 1.8 \text{ V}$, $T_{A} = 25^{\circ}\text{C}$.

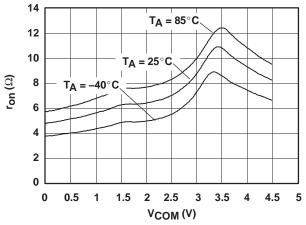


TYPICAL PERFORMANCE



25 T_A = 85°C 20 $T_A = 25^{\circ}C$ 15 $_{\mathsf{lon}}$ (Ω) T_A = -40°C 10 5 0 0 0.5 1 1.5 2 2.5 3 3.5 VCOM (V)

Figure 2. r_{on} vs V_{COM} ($V_{+} = 3 V$)



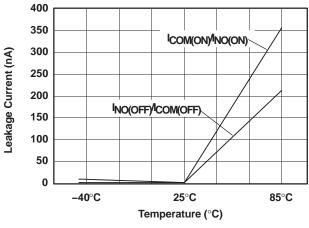
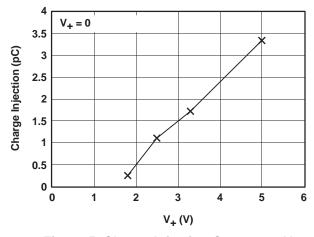


Figure 3. r_{on} vs V_{COM} ($V_{+} = 4.5 \text{ V}$)

Figure 4. Leakage Current vs Temperature $(V_+ = 5 V)$



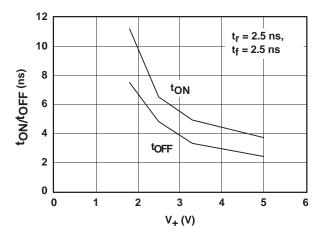


Figure 5. Charge Injection Current vs V₊

Figure 6. toN and toFF vs V+



TYPICAL PERFORMANCE (continued)

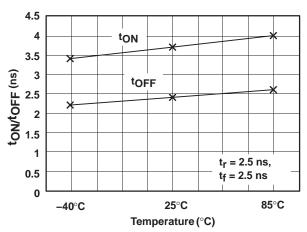


Figure 7. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

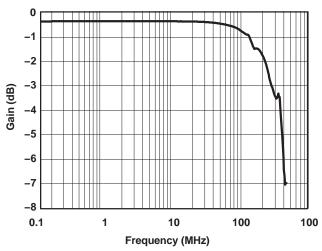


Figure 9. Frequency Response $(V_+ = 3 V)$

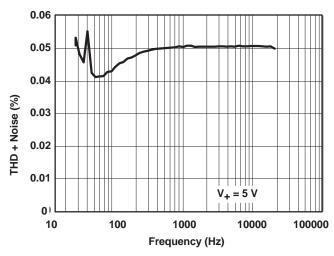


Figure 11. Total Harmonic Distortion vs Frequency $(V_+ = 5 \text{ V})$

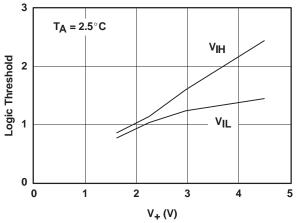


Figure 8. Logic Threshold vs V₊

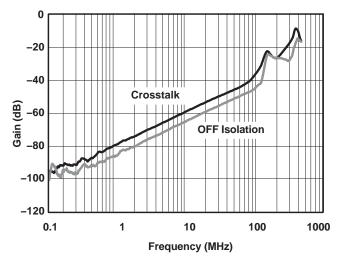


Figure 10. OFF Isolation and Crosstalk vs Frequency ($V_+ = 3 V$)

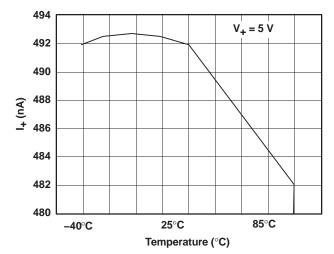


Figure 12. Power Supply Current vs Temperature $(V_+ = 5 V)$



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PIN DESCRIPTION

| PIN NUMBER | NAME | DESCRIPTION |
|------------|----------------|---|
| 1 | NO0 | Normally-open terminal |
| 2 | NO1 | Normally-open terminal |
| 3 | NO2 | Normally-open terminal |
| 4 | GND | Digital ground |
| 5 | IN2 | Digital control pin to connect the COM terminal to the NO terminals |
| 6 | IN1 | Digital control pin to connect the COM terminal to the NO terminals |
| 7 | COM | Common terminal |
| 8 | V ₊ | Power supply |

PARAMETER DESCRIPTION

| SYMBOL | DESCRIPTION |
|-----------------------------------|--|
| VCOM | Voltage at the COM pin. |
| V _{NO} | Voltage at the NO pin. |
| r _{on} | Resistance between COM and NO ports, when the channel is ON. |
| $\Delta r_{\sf on}$ | Difference of r _{on} between channels. |
| ron(flat) | Difference between the maximum and minimum value of ron in a channel over the specified range of conditions. |
| I _{NO(OFF)} | Leakage current measured at the NO port with the corresponding channel (NO to COM) in the OFF-state under worst case input and output conditions. |
| I _{NO(ON)} | Leakage current measured at the NO port with the corresponding channel (NO to COM) in the ON-state and the output (COM) being open. |
| ICOM(OFF) | Leakage current measured at the COM port with the corresponding channel (COM to NO) in the OFF-state under worst case input and output conditions. |
| ICOM(ON) | Leakage current measured at the COM port with the corresponding channel (COM to NO) in the ON-state and the output (NO) being open. |
| V _{IH} | Minimum input voltage for logic high for the control input (IN) |
| V _I L | Maximum input voltage for logic low for the control input (IN) |
| VIN | Voltage at the IN pin. |
| I _{IH} , I _{IL} | Leakage current measured at the IN pin. |
| tON | Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM/NO) signal, when the switch is turning ON. |
| ^t OFF | Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM/NO) signal, when the switch is turning OFF. |
| tBBM | Break-Before-Make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NO), when the control signal changes state. |
| QC | Charge-injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge-injection, $Q_C = C_L \times \Delta V_O$, C_L is the load capacitance and ΔV_O is the change in analog output voltage. |
| C _{NO(OFF)} | Capacitance at the NO port when the corresponding channel (NO to COM) is OFF. |
| C _{NO(ON)} | Capacitance at the NO port when the corresponding channel (NO to COM) is ON. |
| C _{COM(OFF)} | Capacitance at the COM port when the corresponding channel (COM to NO) is OFF. |
| C _{COM(ON)} | Capacitance at the COM port when the corresponding channel (COM to NO) is ON. |
| C _{IN} | Capacitance of the IN input. |



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PARAMETER DESCRIPTION (continued)

| SYMBOL | DESCRIPTION |
|------------------|---|
| O _{ISO} | Off-isolation of the switch is a measurement of off-state switch impedance. This is measured in dB in a specific frequency with the corresponding channel (NO to COM) in the OFF state. |
| XTALK | Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel. This is measured in a specific frequency and in dB. |
| BW | Bandwidth of the switch. This is the frequency where the gain of an ON channel is -3 dB below the DC gain. |
| l ₊ | Static power supply current with the control (IN) pin at V ₊ or GND. |

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PARAMETER MEASUREMENT INFORMATION

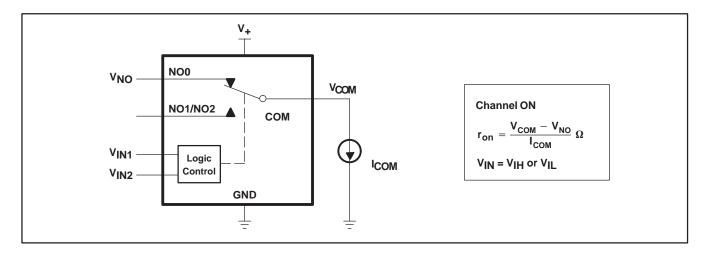


Figure 13. ON-State Resistance (ron)

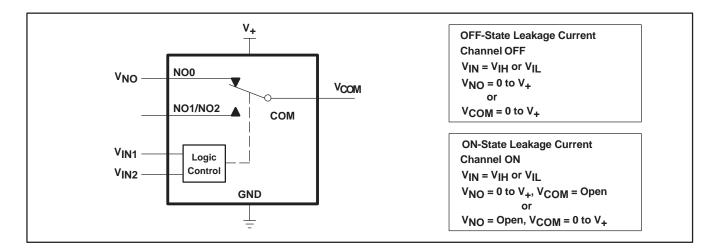


Figure 14. ON and OFF State Leakage Current ($I_{COM(ON)}$, $I_{COM(OFF)}$, $I_{NO(OFF)}$, $I_{NO(ON)}$)

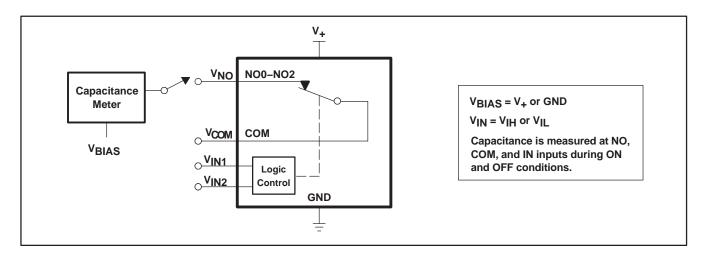


Figure 15. Capacitance (C_{IN} , $C_{COM(ON)}$, $C_{COM(OFF)}$, $C_{NO(OFF)}$, $C_{NO(ON)}$)



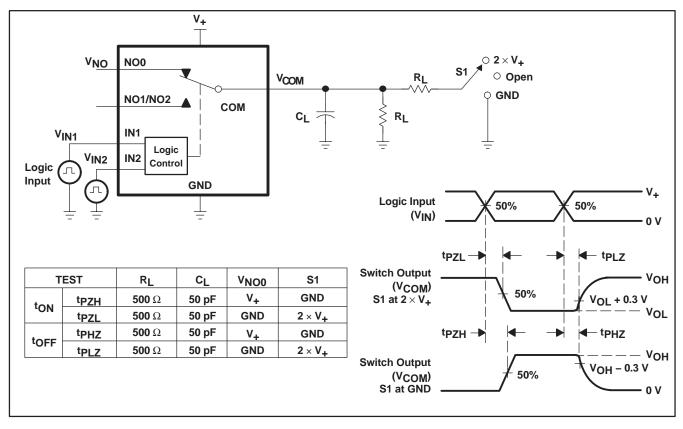


Figure 16. Turn-ON (t_{ON}) and Turn-OFF (t_{OFF}) Time

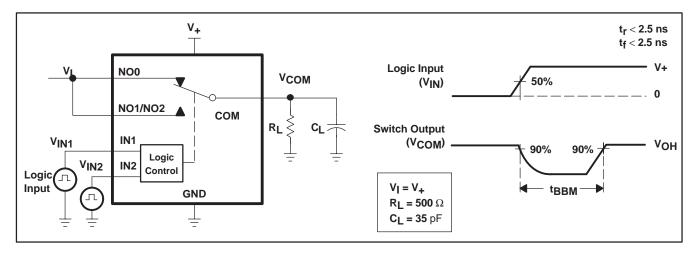


Figure 17. Break-Before-Make (t_{BBM}) Time

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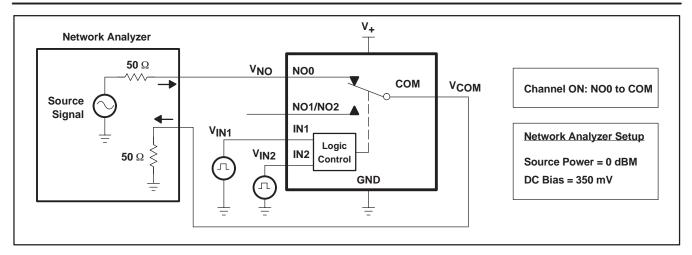


Figure 18. Frequency Response (BW)

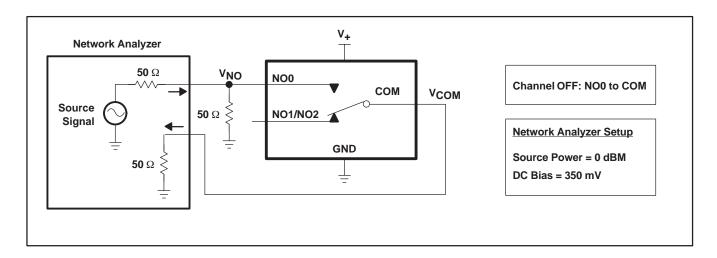


Figure 19. Off-Isolation (OISO)

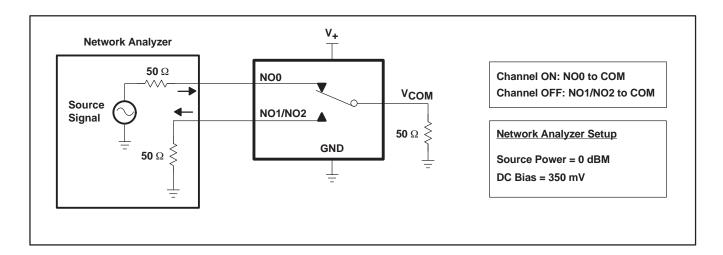


Figure 20. Crosstalk (X_{TALK})



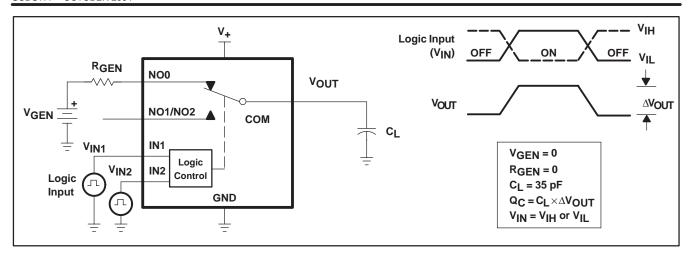
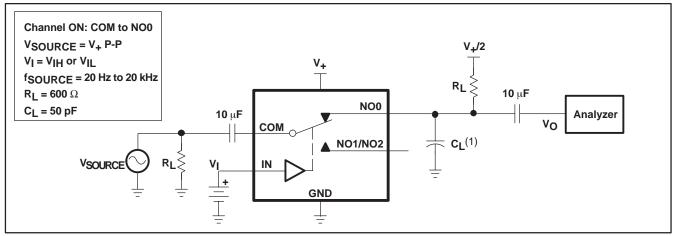


Figure 21. Charge-Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 22. Total Harmonic Distortion (THD)





i.com 24-Jun-2005

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|-----------------|--------------------|------|----------------|-------------------------|------------------|------------------------------|
| TS5A3357DCTR | PREVIEW | SM8 | DCT | 8 | 3000 | TBD | Call TI | Call TI |
| TS5A3357DCUR | ACTIVE | US8 | DCU | 8 | 3000 | Pb-Free (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| TS5A3357DCURE4 | ACTIVE | US8 | DCU | 8 | 3000 | Pb-Free (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| TS5A3357DCUT | ACTIVE | US8 | DCU | 8 | 250 | Pb-Free (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| TS5A3357DCUTE4 | ACTIVE | US8 | DCU | 8 | 250 | Pb-Free (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

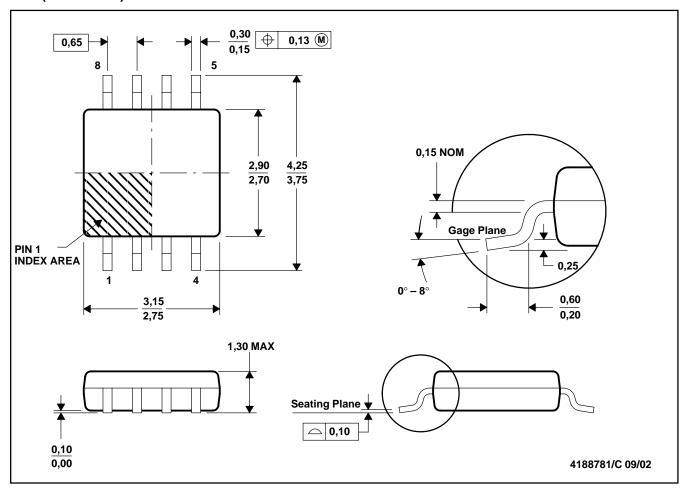
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. Falls within JEDEC MO-187 variation DA.

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- : A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.



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